VT10200C, VFT10200C, VBT10200C, VIT10200C

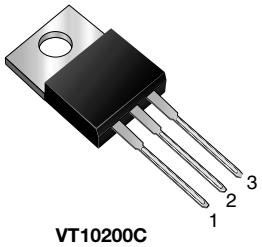
Vishay General Semiconductor

Trench MOS Barrier Schottky Rectifier

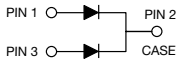
Ultra Low V_F = 0.58 V at I_F = 2.5 A

TMBS®

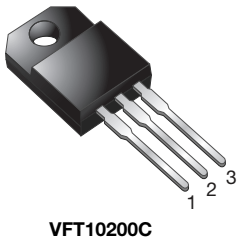
TO-220AB



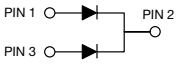
VT10200C



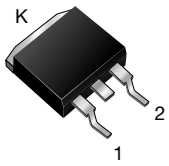
ITO-220AB



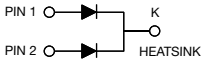
VFT10200C



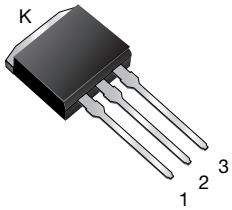
TO-263AB



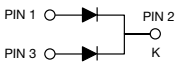
VBT10200C



TO-262AA



VIT10200C



PRIMARY CHARACTERISTICS	
$I_{F(AV)}$	2 x 5.0 A
V_{RRM}	200 V
I_{FSM}	80 A
V_F at I_F = 5.0 A	0.65 V
T_J max.	150 °C

FEATURES

- Trench MOS Schottky technology
- Low forward voltage drop, low power losses
- High efficiency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for TO-263AB package)
- Solder dip 275 °C max. 10 s, per JESD 22-B106 (for TO-220AB, ITO-220AB and TO-262AA package)
- Compliant to RoHS directive 2002/95/EC and in accordance to WEEE 2002/96/EC

Pb e3 RoHS COMPLIANT

TYPICAL APPLICATIONS

For use in high frequency converters, switching power supplies, freewheeling diodes, OR-ing diode, dc-to-dc converters and reverse battery protection.

MECHANICAL DATA

Case: TO-220AB, ITO-220AB, TO-263AB and TO-262AA
Molding compound meets UL 94 V-0 flammability rating
Base P/N-E3 - RoHS compliant, commercial grade

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102
E3 suffix meets JESD 201 class 1A whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS (T_A = 25 °C unless otherwise noted)

PARAMETER		SYMBOL	VT10200C	VFT10200C	VBT10200C	VIT10200C	UNIT
Maximum repetitive peak reverse voltage		V_{RRM}	200				V
Maximum average forward rectified current (fig. 1)	per device	$I_{F(AV)}$	10.0				A
	per diode		5.0				
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode		I_{FSM}	80				A
Non-repetitive avalanche energy at T_J = 25 °C, L = 60 mH per diode		E_{AS}	30				mJ
Peak repetitive reverse current at t_p = 2 µs, 1 kHz, T_J = 38 °C ± 2 °C per diode		I_{RRM}	0.5				A
Voltage rate of change (rated V_R)		dV/dt	10 000				V/µs
Isolation voltage (ITO-220AB only) from terminal to heatsink t = 1 min		V_{AC}	1500				V
Operating junction and storage temperature range		T_J, T_{STG}	- 40 to + 150				°C

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DiodesAmericas@vishay.com, DiodesAsia@vishay.com, DiodesEurope@vishay.com

ELECTRICAL CHARACTERISTICS (T_A = 25 °C unless otherwise noted)						
PARAMETER	**TEST CONDITIONS**		**SYMBOL**	**TYP.**	**MAX.**	**UNIT**
Breakdown voltage	I_R = 1.0 mA	T_A = 25 °C	V_{BR}	200 (minimum)	-	V
Instantaneous forward voltage per diode	I_F = 2.5 A	T_A = 25 °C	V_F (1)	0.81	-	V
	I_F = 5.0 A			1.10	1.60	
	I_F = 2.5 A	T_A = 125 °C		0.58	-	
	I_F = 5.0 A			0.65	0.73	
Reverse current per diode	V_R = 180 V	T_A = 25 °C	I_R (2)	1.7	-	µA
		T_A = 125 °C		1.8	-	mA
	V_R = 200 V	T_A = 25 °C		-	150	µA
		T_A = 125 °C		2.5	10	mA

Notes

(1) Pulse test: 300 µs pulse width, 1 % duty cycle

(2) Pulse test: Pulse width ≤ 40 ms

THERMAL CHARACTERISTICS (T_A = 25 °C unless otherwise noted)							
PARAMETER		**SYMBOL**	**VT10200C**	**VFT10200C**	**VBT10200C**	**VIT10200C**	**UNIT**
Typical thermal resistance	per diode	$R_{\theta JC}$	3.5	7.0	3.5	3.5	°C/W
	per device		2.5	5.5	2.5	2.5	

ORDERING INFORMATION (Example)					
PACKAGE	**PREFERRED P/N**	**UNIT WEIGHT (g)**	**PACKAGE CODE**	**BASE QUANTITY**	**DELIVERY MODE**
TO-220AB	VT10200C-E3/4W	1.88	4W	50/tube	Tube
ITO-220AB	VFT10200C-E3/4W	1.72	4W	50/tube	Tube
TO-263AB	VBT10200C-E3/4W	1.37	4W	50/tube	Tube
TO-263AB	VBT10200C-E3/8W	1.37	8W	800/reel	Tape and reel
TO-262AA	VIT10200C-E3/4W	1.44	4W	50/tube	Tube

RATINGS AND CHARACTERISTICS CURVES

(T_A = 25 °C unless otherwise noted)

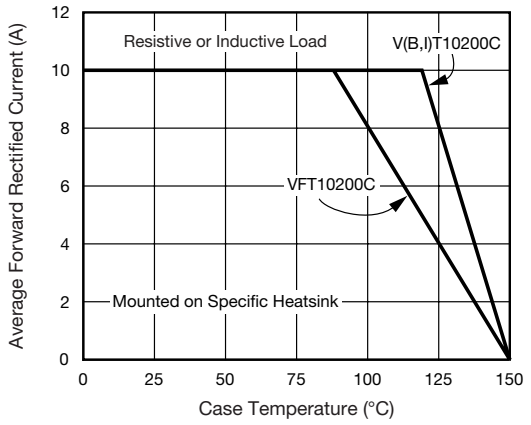

Fig. 1 - Maximum Forward Current Derating Curve

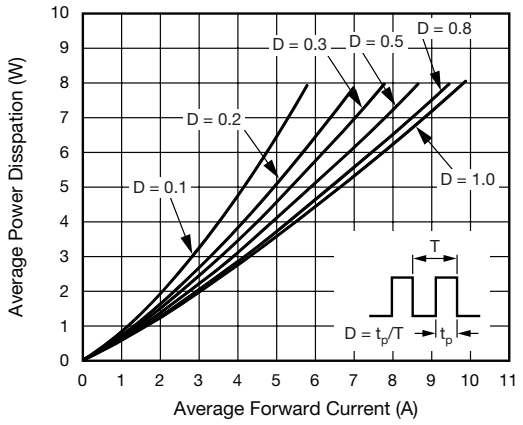

Fig. 2 - Forward Power Loss Characteristics Per Device

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Revision: 09-Dec-09

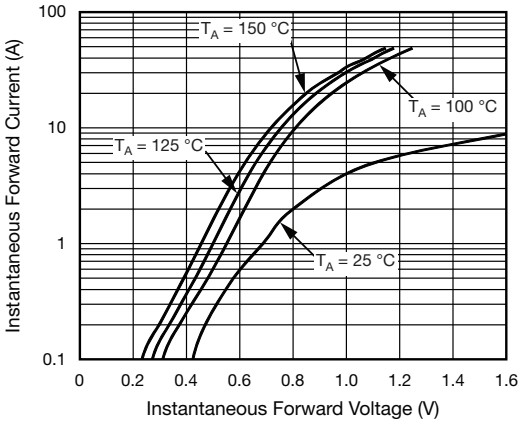


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

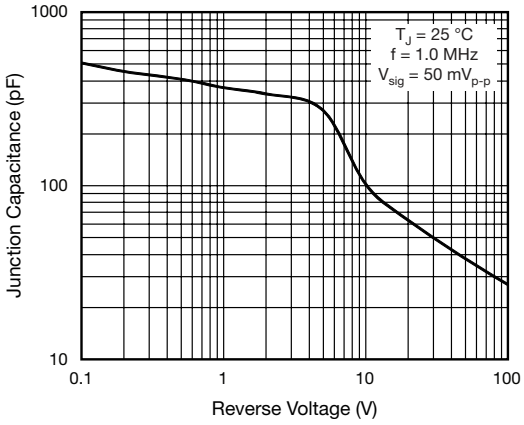


Fig. 5 - Typical Junction Capacitance Per Diode

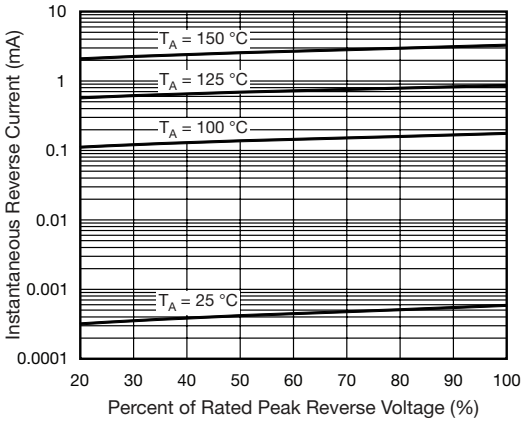


Fig. 4 - Typical Reverse Characteristics Per Diode

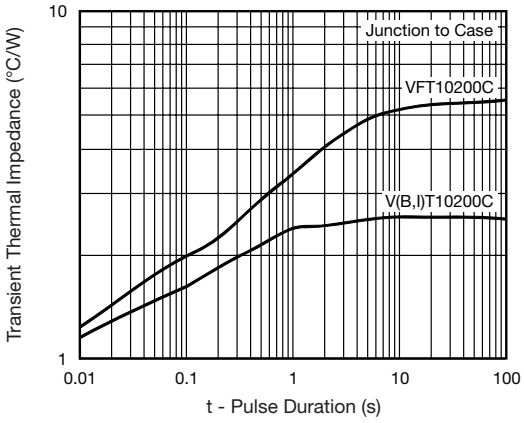
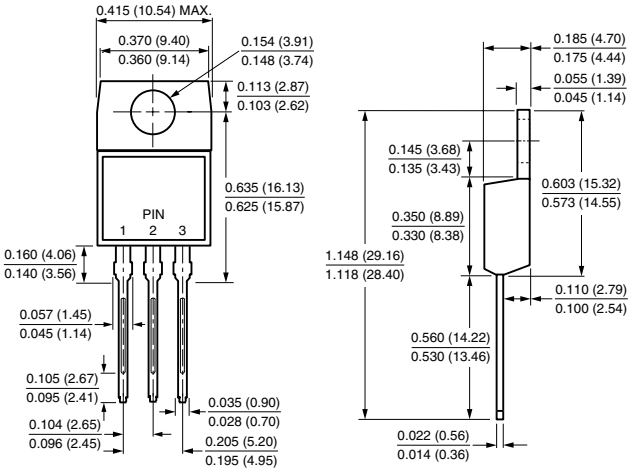


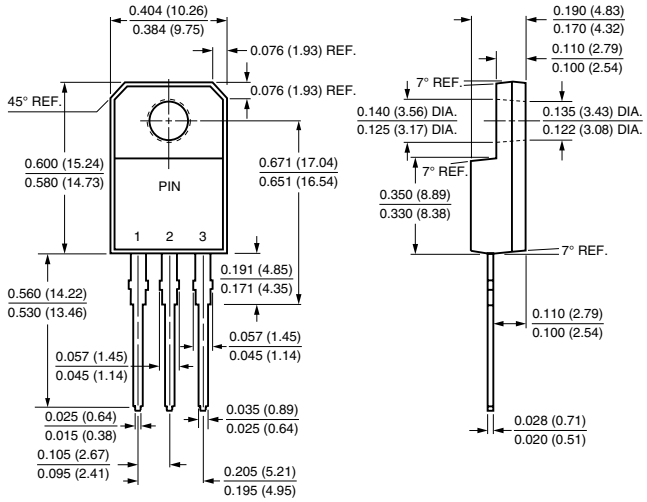
Fig. 6 - Typical Transient Thermal Impedance Per Device

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

TO-220AB



ITO-220AB



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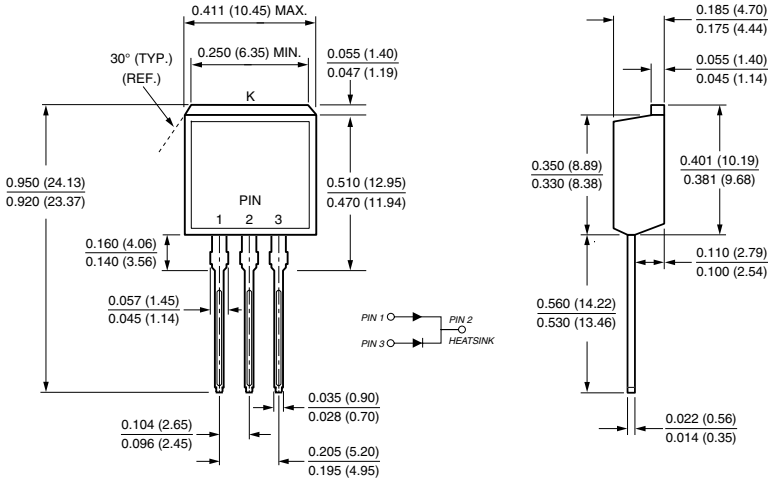
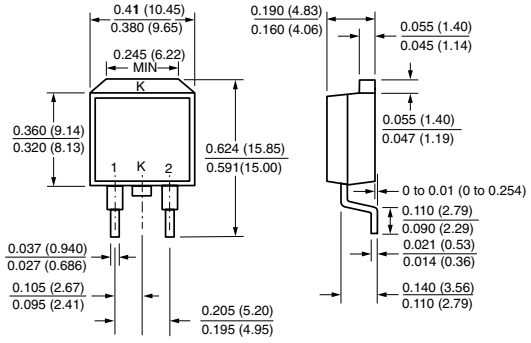
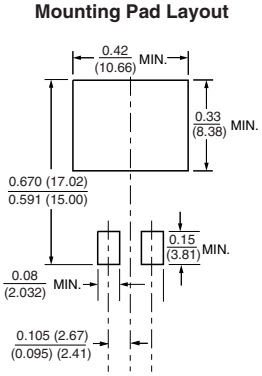


TO-263AB



Mounting Pad Layout



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- Техническая поддержка проекта;
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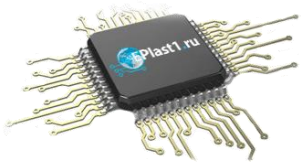

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Телефон: 8 (812) 309 58 32 (многоканальный)
Факс: 8 (812) 320-02-42
Электронная почта: org@eplast1.ru
Адрес: 198099, г. Санкт-Петербург, ул. Калинина, дом 2, корпус 4, литера А.